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Metamaterial-based electromagnetically induced transparency-like sensor design with low-volume sliding dielectric loadings

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Abstract

In this study, tunability of the electromagnetically induced transparency (EIT)-like transmission window by low-volume dielectric loadings is presented both numerically and experimentally in S-band. The EIT-like transmission behavior is obtained by a metamaterial, composed of an electric resonator and a closed-ring resonator patterned on a dielectric substrate. The frequency tuning is obtained by two applications called horizontal sliding application (HSA) and vertical sliding application based on sliding of the low-volume loadings from the edges to geometric center (i.e., inward). For both applications, the frequency tuning has been investigated for dielectric loadings which have relative permittivity of 2.2, 3, 4.5, and 6.15. The results reveal that the proposed sliding applications are effective on tuning the transmission peak frequency. An achieved 1136 and 971 MHz absolute spectral shifts and corresponding 6.34% and 5.41% absolute sensitivities by simulations and measurements, respectively, are the best results which are obtained for HSA at 5 mm shift value. Moreover, 14.67% sensitivity is obtained in simulations for the complete dielectric loading on the resonator in response to the increase in refractive index from 1 to 1.5. It is believed that the proposed applications will contribute to the existent sensing studies.

Introduction

The phenomenon of obtaining a narrower spectral band of transmission in a relatively broad absorption spectrum (i.e., in opaque medium) is called electromagnetically induced transparency (EIT), and it is commonly explained by quantum interference effect [1–5]. In early studies, this phenomenon was seen in the three-level atomic systems which required relatively complex setups with cryogenic temperatures and high intensity laser requirements [4, 5]; however, it had drawn exceedingly attention after adapting to classical systems explained by mechanical oscillators and RLC circuits, and therefore it was called as the EIT-like effect [3–6]. Contingent to this new phenomenon, metamaterial counterparts with EIT-like effect were presented [4–7].

EIT-like phenomena obtained in metamaterial structure are generally realized with two methods: one is the trapped mode resonance [4, 8] and the other is a result of the coupling between dark mode, bright mode, quasi-dark mode, or any binary or ternary combination of them [9–15]. The trapped mode is possible to be produced by breaking structural symmetry and there becomes a weak coupling to the free space [8]. One of the second methods, bright mode-dark mode coupling, exists on the structures (1) having a bright mode resonance with a lower quality (Q) factor which can be excited directly by the incident wave, and (2) dark mode resonance with a larger Q-factor which get no interaction with incident wave and free space [10, 14]. EIT-like metamaterials are frequently used in on slow-light applications [16, 17], light storage [18], modulators [19, 20], and sensors [20–27] with an increasing interest.

In the literature, there are various sensing approaches for solid sample detection with relatively low permittivity range in microwaves [28–39]. An important number of them realize the sensing application by using microstrip line–coupled designs [28, 33–39] or a substrate integrated waveguide sensor design [29]. Moreover, differential sensor designs are also popular that need a second dielectric material or free-space medium as a reference for permittivity detection [30–33, 36, 38].

In this study, two different dielectric loading applications are studied on an EIT-like metamaterial design composed of the electric resonator (ER) and the closed-ring resonator (CRR) in both simulations and experiments. During the analyses, the effects of the dielectric loadings (i.e., the effects of their real part of relative permittivity) on the tunability of the transmission



window in terms of the transmission peak frequency f_0 and Q-factor are investigated. The CRR is a commonly used structure in EIT-like resonator designs [40, 41] as the bright mode resonator with its lower Q-factor in the operation band. On the other hand, the ER serves as a quasi-dark mode resonator in the design. ER is a well-known metamaterial structure [42–45] observed in various applications such as absorber [46–48], sensor [49], polarizer [50], and antenna [51] designs. However, its usage in an EIT-like metamaterial design appears in the conference paper presented by the authors of this study which establishes the early designs and the feasibility of this study in only simulations by using cubic dielectric loadings on the gap regions [15]. It can be noted here that ER is sometimes called an electric LC resonator in the literature [44, 45, 48–50]. The prominent novelties of this study are listed as follows:

- This study presents significantly extended analyses of reference [15] including newer designs adapted for S-band waveguide simulation and experimental setups, two new tuning applications based on sliding of low-volume dielectric loadings, a tuning application based on complete dielectric loadings on the top of the EIT-like metamaterial to reveal the effects of partial loading on the sensitivity, and further analyses including electric field distributions, surface current plots, Q-factor, and dependence of f_0 on the real part of relative permittivity.
- In this study, the proposed applications which are composed of sliding low-volume dielectric loadings on EIT-like metamaterial are new. The applications promise two practical approaches: (1) a displacement sensing by sliding the identical two low-volume dielectrics over the EIT-like metamaterial structure and (2) a low-volume dielectric sensing by fixing the positions of the loadings on the EIT-like structure and changing their dielectric constant.
- In literature, the sensing applications that EIT-like structures take part uses relatively larger sizes of dielectrics (i.e., material under test [MUT]) to cover the entire structure [5, 21, 52–57]. However, in this study, we use low-volume dielectric loadings which cover only a small fraction of the resonator structure.

Design and characterization setups

The schematic from top with design parameters, and the photograph of the proposed EIT-like structure are shown in Fig. 1. The metallic CRR and ER structures was patterned over Rogers RT/duroid^{*} 5880 substrate with relative permittivity $\varepsilon_r = 2.2$ and dielectric loss tangent tan $\delta = 0.0009$. Herein, the thickness of the dielectric substrate is 0.762 mm and the thickness of the metallic conductor (i.e., copper, modeled by conductivity of 58 MS/m) is 17.5 µm. The dimensions of the substrate and the structure are given as $L_x = 72.136$ mm, $L_y = 34.036$ mm, $l_{cv} = 24$ mm, $l_{ch} = 24$ mm, $l_{ev} = 10$ mm, $l_{eh} = 10$ mm, $w_c = 1$ mm, $w_l = 1$ mm, $l_s = 3$ mm, g = 1 mm.

The numerical analyses of the design are carried out by using CST Studio Suite^{*} frequency domain solver by using the simulation setup, as shown in Fig. 2(a). Herein two waveguide ports are placed in the *z*-axis direction, and perfect electrical conductors ($E_t = 0$) are used as the boundary conditions in the remaining directions to limit the computational domain [58]. In simulations, the background medium is modeled by $\varepsilon_r = 1$ and $\mu_r = 1$. For the experimental process, the structure is placed inside the sample holder as shown in Fig. 2(b–d). As the description of the applications a series of photographs, each taken in the sample holder,



Figure 1. The studied EIT-like metamaterial design. (a) The schematic from top with design parameters. (b) The photograph of the fabricated structure.



Figure 2. (a) Simulation and (b) experimental setups for EIT-like metamaterial characterization; (c) a series of photographs, each taken in the sample holder, illustrating the horizontal sliding application; and (d) the layout of EIT-like metamaterial together with dielectric loadings inside the sample holder with supporting pink XPS materials.



Figure 3. The schematic illustrations of the dielectric loading pairs composed of two identical $a \times b$ sized rectangular dielectric pieces in (a) horizontal sliding application and (b) vertical sliding application in six steps.

are presented in Fig. 3(c) illustrating the horizontal sliding application (HSA) as the example. During the experiments, to prevent the unwanted displacements of the dielectric loadings and to minimize the unwanted air gaps between the EIT-like metamaterial



Figure 4. Transmission spectra of (a) individual ER and CRR structures in simulations and (b) EIT-like metamaterial in simulation and measurement.



Figure 5. The surface current densities on EIT-like metamaterial structure. (a) At 3.197 GHz; the first transmission dip frequency, (b) at 3.479 GHz; the transmission peak frequency. and (c) at 3.772 GHz: the second transmission dip frequency.

and the dielectric loadings, extruded polystyrene (XPS) materials (i.e., pink foams observed in Fig. 2(d)) are used as support material. Our previous laboratory analyses revealed that effect of the XPS material might be negligible since it had similar dielectric properties with air [59]. Moreover, WR-284 coaxial to waveguide adaptors are used to connect the waveguide transmission line to the Agilent FieldFox N9926A vector network analyzer. Considering the cutoff frequencies of the first two propagating modes of a rectangular waveguide [60] together with the frequency band under investigation, only TE₁₀ mode propagates in the simulation and experimental setups, where the wave propagation is along z direction, the electric field is along y direction, and the magnetic field is along x and z directions. However, the effects of H_z field, which has cosine variation [60], on the excitation of the structure may be neglected since the metallic structure is placed around the center of the waveguide cross section [61].

Figure 3 illustrates the two proposed dielectric loading mechanisms schematically, namely HSA and vertical sliding application (VSA) for tuning of the transmission window or tuning the of transmission peak frequency. HSA and VSA represent the applications where the loadings are positioned vertically and horizontally, respectively. As seen in the figure, the dielectric loadings are shifted gradually toward the geometric center of structure (i.e., inward) with the shift parameter s_h for HSA and s_v for VSA. For the proof of concept, the dielectric materials used as the dielectric loadings are uncladded Rogers RT/duroid[®] 5880 ($\varepsilon_r = 2.2$ and tan $\delta = 0.0009$), Rogers CLTE-AT^{**} ($\varepsilon_r = 3$ and tan $\delta = 0.0013$), Arlon AD450 ($\varepsilon_r = 4.5$ and tan $\delta = 0.0035$), and Rogers RO4360G2TM ($\varepsilon_r = 6.15$ and tan $\delta = 0.0038$) having thicknesses of 1.58, 1.524, 1.524, and 1.524 mm, respectively. During the analyses, the side lengths of the loadings are kept constant at a = 22 mm and b = 6 mm (see Fig. 3). In the simulations, the loadings are lifted as much as the metallic line thickness (i.e., $17.5 \,\mu$ m) to avoid any intersections between the dielectric loadings and the metallic resonator line. Considering the

two proposed sliding applications; it can be said that it is important for the EIT-like metamaterial unit-cell to be symmetrical in the design along horizontal and vertical directions.

Results and discussion

The transmission (i.e., $|S_{21}|$) spectra of the individual unloaded (i.e., bare) CRR and ER structures in simulations and the unloaded EIT-like metamaterial structure in simulations and measurements are presented in Fig. 4(a) and (b), respectively. In Fig. 4(a), the individual CRR and ER are shown to possess a transmission dip at 3.372 and 3.607 GHz, respectively. On the other hand, the composition of them, i.e., the EIT-like metamaterial, has two transmission dips and one transmission peak in the frequency band of investigation. In more detail, the dips are observed at 3.197 and 3.772 GHz in simulations and observed at 3.193 and 3.779 GHz in measurements. In addition, the transmission peak frequency f_0 is observed at 3.479 GHz in simulation and at 3.484 GHz in measurement. Figure 4(b) reveals that the simulated and the measured transmission spectra agree very well. In the design, CRR and the ER have the role of the bright and the quasi-dark mode resonators, respectively.

To figure out the resonance behavior of the EIT-like metamaterial, the surface current densities are plotted at 3.197, 3.479, and 3.772 GHz, as shown in Fig. 5. The plots at each frequency support that the ER has circulating current densities, which is the identifier of an *LC* resonance [19, 22, 44] and the CRR has stronger surface currents at the vertical edges which are parallel to direction of the incident electric field vector; hence, this resonance can be described as an electric dipole resonance [40]. In all, the surface current densities are strongest at 3.479 GHz where the transmission peak is observed.

The $|S_{21}|$ plots regarding the tuning application for HSA at the shift values $s_h = 0 \text{ mm}$ and $s_h = 5 \text{ mm}$, and for VSA at the shift values $s_v = 0 \text{ mm}$ and $s_v = 5 \text{ mm}$ are shown in Figs. 6 and 7, respectively. Since the transmission plots for s_h and s_v values from 2 to 4 present similar behaviors with the those observed for the extremes (i.e., 0 and 5 mm), the transmission spectra are only presented for 0 and 5 mm shift values for four dielectric loading cases together with the bare ones. However, all aggregate results will be discussed through Fig. 9.

In Figs. 6 and 7, the bare MUT designates the air which is chosen as the starting point of the permittivity level (i.e., $\varepsilon_r = 1$). For HSA at $s_h = 0$ mm, as the real part of relative permittivity of the MUT is increased from 1 to 6.15 (i.e., from bare to RO4360G2^m), f_0 reduces from 3.479 to 3.175 GHz in simulations and from 3.484 to



Figure 6. Transmission spectra of the bare and the dielectric-loaded EIT-like metamaterials in horizontal sliding application. (a) $s_h = 0$ mm simulations, (b) $s_h = 0$ mm measurements, (c) $s_h = 5$ mm simulations, and (d) $s_h = 5$ mm measurements.

Figure 7. Transmission spectra of the bare and the dielectric-loaded EIT-like metamaterials in vertical sliding application. (a) $s_v = 0$ mm simulations, (b) $s_v = 0$ mm measurements, (c) $s_v = 5$ mm simulations, and (d) $s_v = 5$ mm measurements.

3.195 GHz in measurements, systematically. Alternatively, for VSA at $s_v = 0$ mm, as the real part of relative permittivity of the MUT is changed from bare to RO4360G2^m, the frequency of the transmission peak reduces from 3.479 to 3.118 GHz in simulations and from 3.484 to 3.182 GHz in measurements. The behavior of f_0 is very

similar for the two applications; however, the transmission bandwidths get effected differently. In more detail, although the transmission bandwidths are nearly the same as the MUT is changed from the bare to RO4360G2^m for HSA at $s_h = 0$ mm, they obviously broaden for VSA at $s_v = 0$ mm. This behavior can be explained by



Figure 8. Electric field distribution on the bare EIT-like metamaterial. (a) At 3.197 GHz; the first transmission dip frequency, (b) at 3.479 GHz; the transmission peak frequency, and (c) at 3.772 GHz; the second transmission dip frequency.

the use electric field distributions over the bare EIT-like metamaterial as shown in Fig. 8. First, the electric field distributions at the first null of the EIT-like transmission (i.e., at 3.197 GHz) are especially higher at the top and bottom edges of the CRR and around the gap positions of the ER. Second, the field distributions at the EITlike transmission peak frequency f_0 (i.e., at 3.479 GHz) are higher mainly on ER but also on the top and bottom edges of the CRR. Moreover, the field distributions are the highest here in strength among the three cases. Lastly, the electric field distributions at the second null of the EIT-like transmission (i.e., at 3.772 GHz) are higher at the gap positions of the ER, on the other hand there are still high electric field distributions around the top and bottom edges of the CRR. However, the field distributions around the top and bottom edges are observed to be significantly reduced as compared with that of the first null. Since in HSA at $s_h = 0 \text{ mm}$ case, the dielectric loadings are along the vertical arms of the CRR (see Fig. 3(a)) and tangent to the gaps of the ER, all the two dips and the transmission peak get effected similarly and simultaneously, and the transmission bandwidth is not affected significantly. However, in VSA at $s_v = 0$ mm case, the dielectric loadings lie inbetween the horizontal edges (i.e., top and bottom) of the CRR and the ER. Therefore, the frequencies of the first transmission minimum and the transmission peak slides down more than the second transmission minimum. This application yields a band broadening. As a measure of change in the transmission bandwidth, the quality factor is calculated by Q-factor = f_0 /FWHM, where FWHM is the full width at half maximum, and it is calculated as the frequency band between the value corresponding to the average of the maximum and minimum values of the transmitted power [62, 63]. Figure 9 shows the calculated Q-factor values by using the simulation and the measurement results for both HSA and VSA at several shift values. Supporting the above observations, for HSA at $s_h = 0$ mm case, Q-factor does not significantly change; however, it gradually decreases for VSA at $s_v = 0$ mm case.

Now, we investigate the behaviors of the EIT-like transmission window in response to the change in real part of relative permittivity of the MUT at the second extremes, i.e., at $s_h = 5$ mm and $s_v = 5$ mm for the HSA and VSA, respectively. For HSA at $s_h = 5$ mm, as the real part of relative permittivity of the MUT is increased from 1 to 6.15 (i.e., from bare to RO4360G2^{∞}), f_0 reduces from 3.479 to 2.343 GHz in simulations and reduces from 3.484 to 2.513 GHz in measurements, systematically. Alternatively,

for VSA at $s_{\nu} = 5$ mm, as the real part of relative permittivity of the MUT is changed from bare to RO4360G2[™], the frequency of the transmission peak reduces from 3.479 to 2.393 GHz in simulations and reduces from 3.484 to 2.622 GHz in measurements. Here we have three important observations: First, f_0 of the EITlike metamaterial becomes more sensitive to the real part of relative permittivity of the dielectric loadings at 5 mm shift cases than that at 0 mm shift cases for both applications. This is not a surprising behavior if we consider Fig. 8 again, since the electric field distribution is highly concentrated on the ER at f_0 . At 5 mm shift cases, the dielectric loadings completely cover up the ER, and hence they have greatest effect on the f_0 change, i.e., sensitivity. In literature, the sensitivity (S) is used as a measure which is defined by the ratio difference between the resonance frequencies to the difference between the real part of relative permittivities of the loadings [27, 31-33]. Second, for both HSA and VSA at 5 mm shift cases, as the real part of relative permittivity of the dielectric loadings increases, the overall structure tends to behave like a CRR-only resonator since the resonance frequency of the individual ER reduces much rapidly than that of CRR and the effect of the CRR become more dominant on the transmission characteristics. Ultimately, EIT-like transmission peak almost disappears in the simulations of RO4360G2[™]-loaded EIT-like metamaterial at $s_v = 5$ mm. There still exists a reduced transmission peak in the related measurement result (see Fig. 7(b)); however, its trend reveals that further increment in the real part of relative permittivity will destroy the EIT-like transmission. Lastly, for 5 mm shift cases, there are obvious changes in the Q-factor observed even by naked eye in Fig. 6(c) and (d) for HSA and in Fig. 7(c) and (d) for VSA. This observation is supported by Fig. 9. In addition to that, Fig. 9 clearly reveals that the Q-factor is dependent on the shift values; however, this dependence is highest in 5 mm shift cases.

The simulation results given in Fig. 10 show that for both HSA and VSA, f_0 chances faster in response to the change in the real part of relative permittivity as the shift amount increases. According to sensitivity, defined above, this means that the sensitivity increases as the shift amount increases and ultimately the sensitivities become maximum for 5 mm shift cases. Moreover, change in f_0 with respect to the real part of relative permittivity change gradually increases with increasing s_h value in HSA. However, it increases significantly in VSA starting with $s_v = 4$ mm. In other words, it can be said that f_0 in HSA is more sensitive than that of VSA to the shift value and the real part of relative permittivity of the dielectric loadings. This observation makes HSA more advantageous in terms of sensitivity and makes it a preferable candidate for a sensing application. On the other hand, Fig. 10 is another indicator showing that the proposed approach is clearly sensitive to the changes in s_h and s_v at fixed relative permittivity values. Although some experimental measurement errors are noticeable, the measurement results in Fig. 10 are consistent with the simulation results.

Table 1 shows the f_0 values obtained by simulations and measurements for $s_h = 5$ mm case of HSA, where f_0 is most dependent on the permittivity of the dielectric loadings ε_r . The data show that the f_0 of HSA for $s_h = 5$ mm is reduced from 3.479 to 2.343 GHz in simulations and it is reduced from 3.484 to 2.513 GHz in measurements as ε_r is increased from 1 to 6.15 which correspond to 1.136 GHz (32.65%) and 0.971 GHz (27.87%) shifts in f_0 in simulations and experiments, respectively.

In this study, we performed analyses in both simulations and experimental measurements. In general, the results show good agreements. However, it is important to discuss here that there are



Figure 9. Calculated Q-factors. (a) Horizontal sliding application simulations, (b) horizontal sliding application measurements, (c) vertical sliding application simulations, and (d) vertical sliding application measurements.

Figure 10. Frequency of transmission peak (i.e., f_0) versus real part of relative permittivity of the dielectric loadings. (a) Horizontal sliding application simulations, (b) horizontal sliding application measurements, (c) vertical sliding application simulations, and (d) vertical sliding application measurements.

some discrepancies in terms of resonance frequencies, transmission amplitudes, or bandwidths. These discrepancies are supposed to be mainly due to the unavoidable additional air gaps between the dielectric loading and the EIT-like metamaterial since the structures do not have ideally flat surfaces. Although using an XPS material in the measurements as a support structure to avoid these additional air gaps is an effective approach depending on our laboratory experiences, it cannot fully provide the ideal simulation setup. Another reason of the discrepancies may be deviations in the dielectric properties of the dielectric loadings with respect to

Table 1. Dependence of f_0 on $\varepsilon_{\rm r}$ in the case of $s_h=5$ mm of horizontal sliding application

Sample	Simulated f_0 (GHz)	Measured f_0 (GHz)	$\varepsilon_{ m r}$
Bare	3.479	3.484	1
5880	3.039	3.160	2.2
CLTE-AT™	2.842	2.942	3
AD450	2.566	2.781	4.5
RO4360G2™	2.343	2.513	6.15

the catalog values. We cannot see fabrication errors as a factor here because, there is nearly a perfect agreement between the simulation and experimental results of the bare (unloaded) EIT-like metamaterial.

To complete the study, additional numerical analyses were performed for a fairer comparison with the related literature. This time, the resonator side of the studied EIT-like metamaterial unit cell surface was completely loaded (i.e., covered) with a 10-mmthick lossless dielectric (i.e., 72.136 mm × 34.036 mm × 10 mm) just on the Rogers RT/duroid^{*} 5880 substrate in the simulation environment. The usage of EIT-like designs for refractive index (*n*) sensing applications is common [21-26, 53-56]. Therefore, the refractive index of the dielectric is increased from 1 to 1.5, which corresponds to an increase in ε_r from 1 to 2.25, since $n = \sqrt{\varepsilon_r}$ considering $\mu_r = 1$ [23], as the parametric study and transmission spectra are obtained. The simulation results and schematics of the application are shown in Fig. 11. The results reveal that the frequency of transmission peak lowers from 3.479 to 2.841 GHz as the refractive index increases from 1 to 1.5 which corresponds to 0.638 GHz (18.34%) shift in f_0 .

To clarify the structural and performance differences of this study as compared to the related EIT-like sensor studies given in the literature, whose mechanism are based on sensing the dielectric constant or refractive index changes of the dielectric loadings (i.e., MUT), Table 2 is presented. The comparison parameters in the table are refractive index *n* or dielectric constant ε_r range, frequency region, test setup, MUT settling, position adjustability of MUT, and absolute percentage sensitivity (% |S|). For Table 2, the % *S* values are calculated using equation (1) [27].

$$\%S = \frac{\Delta f}{\Delta \varepsilon_{\rm r} \cdot f_0} \times 100 \tag{1}$$

10 mm

(b)

(c)

where $\Delta f = f_2 - f_1$ is the spectral change in the EIT-like peaks in the transmission, $\Delta \varepsilon_r = \varepsilon_{r2} - \varepsilon_{r1}$ is change in the permittivity, and f_0 is EIT-like peak frequency of the bare (i.e., unloaded) case. In the table, given *n* values are converted to permittivity by using $n = \sqrt{\varepsilon_r}$ considering $\mu_r = 1$ [23]. In the formulation, f_1 corresponds to the resonance frequency where MUT's permittivity is ε_{r1} , and similarly f_2 corresponds to the resonance frequency where MUT's permittivity is ε_{r2} . For the case of $\varepsilon_{r1} = 1, f_0$ will be equal to f_1 ; however, this is not a requirement as can be seen in reference [25]. If the percentage sensitivity values were given in the articles compared in Table 2, we used it directly, if not, we calculated it by using the data or graphs in the related article. For this reason, there may be small deviations due to reading errors from the graph.

Table 2 reveals that there are three prominent directions of our study. First, the partial coverage of the unit-cell by MUT (i.e., referred to as POR in the table) instead of complete coverage. Second, sensing mechanism based on position adjustability of the MUT, and third, relatively high sensitivity values for the complete coverage scenario (i.e., referred to as COR in the table). The first is believed to be an advantage in sensing applications terms of using small amount of analyte material (i.e., MUT), the second provides an important flexibility for adopting the design in mechanical sensing approaches, and the last is obviously preferred in many sensing applications. For the COR scenario, our EIT-like metamaterial shows 14.67% sensitivity, and it is the second highest percentage sensitivity in the table. For the POR scenario, the sensitivity is reduced in both simulations (6.34%) and experiments (5.41%) as expected with respect to the COR case, since the amount of MUT is reduced. However, these sensitivities are still comparable to references [23, 24, 26] and [27]. In addition to those benefits, we use a rectangular hollow waveguide setup for the characterization of EIT-like sensor performance. The main advantage of the waveguide setup is presenting an array behavior with a single unit cell [61] which again provides an important advantage to reduce the applied total MUT amount.

Conclusion

An EIT-like metamaterial structure operating in the S-band is designed, fabricated, and analyzed numerically and experimentally. Tuning of the EIT-like transmission window is studied by low-volume solid dielectric loadings in two different sliding applications (i.e., HSA and VSA) and for several real part of relative permittivity values of the dielectric loadings from 1 (bare) to 6.15

Figure 11. Sensing performance of the 10-mm-thick dielectric-loaded EIT-like metamaterial. (a) Transmission spectra for several refractive indexes. (b) Perspective and (c) side views of 10-mm-thick dielectric-loaded EIT-like metamaterial.

3.0 3.2 3.4

Frequency [GHz]

3.6 3.8 4.0

1.0 0.9 0.8 0.7 0.6 0.5

0.4 0.3 0.2 0.1

0.0

(a)

2.2 2.4

2.6 2.8

Ref.	<i>n</i> Range	$\varepsilon_{ m r}$ Range	Sim./Meas.	Frequency region	Test setup	MUT settling	Position adjustability	Absolute sensitivity S (%)
[21]	1-1.5	-	Sim.	Microwave	Free space	COR	No	11.06
[22]	1-1.3	-	Sim.	Microwave	Free space	SM	No	16.13
[22]	1-2	-	Sim.	Microwave	Free space	SM	No	10.25
[23]	-	1-3	Sim.	Microwave	Free space	COR	No	7.46
[24]	1-1.3	-	Sim.	Microwave	Free space	SM	No	7.17
[25]	1.332-1.372	-	Meas.	THz	Free space	COR	No	10.64
[26]	1-2.5	-	Sim.	THz	Free space	COR	No	4.1
[27]	-	~20-80	Meas.	Microwave	MSTL	COR	No	0.05
	-	1-6	Sim.	Microwave	MSTL	COR	No	5
[55]	1-1.4	-	Sim.	THz	Free space	SM	No	9.97
This study	1-1.5	-	Sim.	Microwave	Waveguide	COR	No	14.67
This study	-	1-6.15	Sim.	Microwave	Waveguide	POR	Yes	6.34
This study	-	1-6.15	Meas.	Microwave	Waveguide	POR	Yes	5.41

Table 2. Comparison of EIT-like sensors in terms of various parameters

COR = completely on the resonator, POR = partially on the resonator, SM = surrounding medium, MSTL = microstrip transmission line

(RO4360G2TM). In HSA, the dielectric loadings are placed along the vertical edges of the CRR, and in VSA, they are placed along the horizontal edges. The results show that not only the transmission peak frequency f_0 but also the transmission bandwidth (i.e., Q-factor) are sensitive to the real part of relative permittivity and the position of the dielectric loadings for both mechanisms. However, HSA is more sensitive than VSA in terms of both shifting value and the real part of relative permittivity. In HSA for $s_h = 5 \text{ mm case}, f_0$ is reduced from 3.479 to 2.343 GHz in simulations and it is reduced from 3.484 to 2.513 GHz in measurements as ε_r is increased from 1 to 6.15. These values correspond to 1.136 GHz (32.65%) and 0.971 GHz (27.87%) shifts in f_0 in simulations and experiments, respectively. The results show that HSA is an effective approach to tune the EIT-like transmission window although low-volume dielectric loadings are used. According to the results, 6.34% and 5.41% absolute sensitivities by simulations and measurements, respectively, are the best sensitivity results which are obtained for HSA at 5 mm shift case. In addition, 14.67% sensitivity value is obtained for the complete dielectric loading case in response to the increase in refractive index from 1 to 1.5. The results show that the proposed approach can be easily adapted for position and dielectric constant sensing applications. As the future work, we plan to study on an electrical circuit model for the design to explain the operating principle and the effects of dielectric loadings with another approach.

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Competing interests. None.

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